TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX74F,TC74LVX74FN,TC74LVX74FT

Dual D-Type Flip-Flop with Preset and Clear

The TC74LVX74F/ FN/ FT is a high-speed CMOS D-flip flop fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

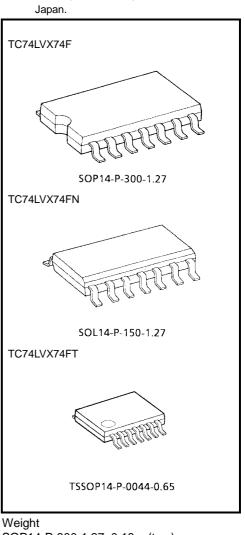
The signal level applied to the D input is transferred to Q output during the positive going transition of the CK pulse.

 $\overline{\text{CLR}}$ and $\overline{\text{PR}}$ are independent of the CK and are accomplished by setting the appropriate input low.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High-speed: $f_{max} = 145 \text{ MHz} (typ.) (V_{CC} = 3.3 \text{ V})$
- Low power dissipation: $I_{CC} = 2 \mu A (max) (T_a = 25^{\circ}C)$
- Input voltage level: $V_{IL} = 0.8 V (max) (V_{CC} = 3 V)$
 - $V_{IH} = 2.0 V (min) (V_{CC} = 3 V)$
- Power-down protection provided on all inputs
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Pin and function compatible with 74HC74

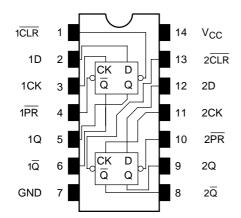


Note: xxxFN (JEDEC SOP) is not available in

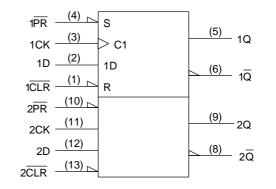
SOP14-P-300-1.27: 0.18 g (typ.) SOL14-P-150-1.27: 0.12 g (typ.) TSSOP14-P-0044-0.65: 0.06 g (typ.)

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Pin Assignment (top view)



IEC Logic Symbol



Truth Table

	Inputs			Out	puts	Function
CLR	PR	D	СК	Q	IQ	T difetion
L	Н	Х	Х	L	Н	Clear
Н	L	Х	Х	Н	L	Preset
L	L	Х	Х	Н	Н	—
Н	н	L		L	Н	—
Н	Н	Н		Н	L	
Н	Н	Х		Qn	Qn	No change

X: Don't care

Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	V _{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I _{IK}	-20	mA
Output diode current	I _{OK}	±20	mA
DC output current	IOUT	±25	mA
DC V _{CC} /ground current	ICC	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65 to 150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 3.6	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

Electrical Characteristics

DC Characteristics

Characteristics		Sym-	Sym- bol Test Condition			Ta = 25°C		Ta = −40 to 85°C		Unit	
				$V_{CC}(V)$	Min	Тур.	Max	Min	Max		
					2.0	1.5	_	_	1.5	_	
	H-level	VIH		—	3.0	2.0	_	_	2.0		
					3.6	2.4	_	_	2.4	_	V
Input voltage		VIL	_		2.0	_	_	0.5		0.5	v
	L-level				3.0	_	_	0.8		0.8	
					3.6	_	_	0.8	_	0.8	
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	_	1.9	_	
				I _{OH} = -50 μA	3.0	2.9	3.0	_	2.9	_	
				$I_{OH} = -4 \text{ mA}$	3.0	2.58	_	_	2.48	_	v
Output voltage		V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0	0.1	_	0.1	v
	L-level			I _{OL} = 50 μA	3.0	_	0	0.1	_	0.1	
				$I_{OL} = 4 \text{ mA}$	3.0	_	_	0.36	_	0.44	
Input leakage current		I _{IN}	$V_{IN} = 5.5 \text{ V or GND}$		3.6	_	_	±0.1	—	±1.0	μA
Quiescent supply cu	urrent	ICC	$V_{IN} = V_{CC}$	or GND	3.6	_		2.0		20.0	μA

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C	Ta = −40 to 85°C	Unit	
			$V_{CC}(V)$	Limit	Limit		
Minimum pulse width	t _{W (L)}		2.7	8.5	10.0	ns	
(CK)	t _{W (H)}	—	$\textbf{3.3}\pm\textbf{0.3}$	6.0	7.0		
Minimum pulse width	4		2.7	8.5	10.0	ns	
(CLR , PR)	t _{W (L)}	—	$\textbf{3.3}\pm\textbf{0.3}$	6.0	7.0		
Minimum set-up time	+		2.7	8.0	9.5	ns	
Minimum set-up time	t _s	—	$\textbf{3.3}\pm\textbf{0.3}$	5.5	6.5	115	
Minimum hold time	+.		2.7	0.5	0.5	- ns	
	t _h	—	$\textbf{3.3}\pm\textbf{0.3}$	0.5	0.5		
Minimum removal time				6.5	7.5	20	
(CLR , PR)	t _{rem}		$\textbf{3.3}\pm\textbf{0.3}$	5.0	5.0	ns	

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
			$V_{CC}(V)$	C _L (pF)	Min	Тур.	Max	Min	Max	
	t-111		2.7	15		7.3	15.0	1.0	18.5	
Propagation delay time	t _{pLH}		2.1	50	_	9.8	18.5	1.0	22.0	ns
(CK-Q, Q)	t		3.3 ± 0.3	15		5.7	9.7	1.0	11.5	115
	t _{pHL}		5.5 ± 0.5	50		8.2	13.2	1.0	15.0	
	t _{pLH}	_	2.7	15		8.4	15.6	1.0	18.5	- ns - - MHz
Propagation delay time				50		10.9	19.1	1.0	22.0	
$(\overline{CLR}, \overline{PR} - Q, \overline{Q})$	t _{pHL}		$\textbf{3.3}\pm\textbf{0.3}$	15		6.6	10.1	1.0	12.0	
				50		9.1	13.6	1.0	15.5	
			2.7 3.3 ± 0.3	15	55	135	_	50	_	
Maximum clock frequency	f _{max}			50	45	60		40		
	יmax			15	95	145		80		
				50	60	85		50		
Output to output skew	t _{osLH}	(Note 1)	2.7	50	_		1.5		1.5	ns
	t _{osHL}		$\textbf{3.3}\pm\textbf{0.3}$	50			1.5		1.5	113
Input capacitance	C _{IN}			(Note 2)		4	10		10	pF
Power dissipation capacitance	C _{PD}			(Note 3)		25	_		—	pF

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

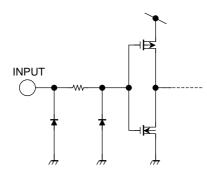
- Note 2: Parameter guaranteed by design.
- Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation: $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per F/F)}$

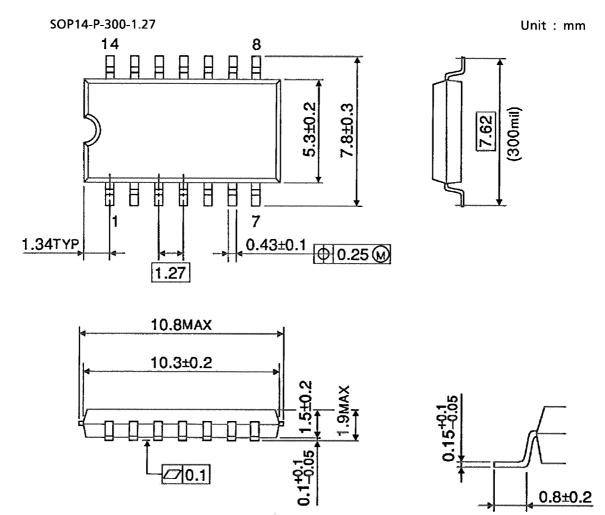
Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3 \text{ ns}$, $C_L = 50 \text{ pF}$)

Characteristics		Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic	V _{OL}	V _{OLP}	_	3.3	0.3	0.5	V
Quiet output minimum dynamic	V _{OL}	V _{OLV}	_	3.3	-0.3	-0.5	V
Minimum high level dynamic input voltage	VIH	V _{IHD}	—	3.3	_	2.0	V
Maximum low level dynamic input voltage	VIL	V _{ILD}	_	3.3		0.8	V

Input Equivalent Circuit

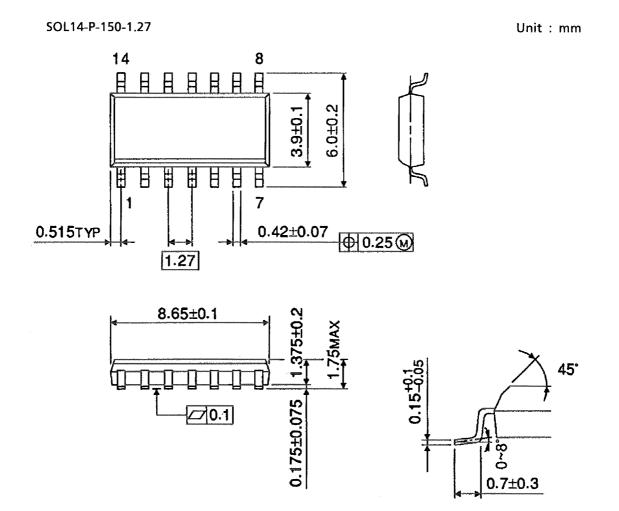


Package Dimensions



Weight: 0.18 g (typ.)

Package Dimensions

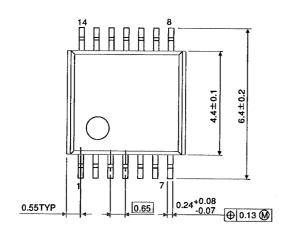


Weight: 0.12 g (typ.)

Unit : mm

Package Dimensions

TSSOP14-P-0044-0.65



5.25MAX

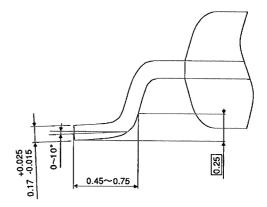
5.0±0.1

- [] 0.1

1.0±0.05 .2MAX

0.1±0.05





Weight: 0.06 g (typ.)

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